# NSN 5961-01-247-1382

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## Inclosure Material:

Metal

**Overall Length:** 

1.550 inches

# **Overall Height:**

0.300 inches

**Overall Width:** 

1.050 inches

# **Mounting Facility Quantity:**

2

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

## **Mounting Method:**

Unthreaded hole

Features Provided:

## Hermetically sealed case

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

700.0 collector-to-emitter, with voltage between base and emitter and 600.0 collector-to-emitter, substaining voltage, base open-circuited and 8.0 emitter to base, rms

## **Current Rating Per Characteristic:**

10.00 amperes source cutoff current and 7.00 amperes source cutoff current

## Power Rating Per Characteristic:

175.0 watts small-signal input power, common-collector absolute

#### Transfer Ratio:

10.0 static forward current transfer ratio, common-emitter

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Terminal Type And Quantity:**

2 tab, solder lug and 1 case

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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